



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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企业微信二维码



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Feature

- $BV_{CEO} > 60V$
- $I_C = 1A$ Continuous Collector Current
- $V_{CE(SAT)} = 0.5V @ 1A$
- 500mW Power Dissipation
- Low Saturation Voltage
- High h_{FE} Min 300@250mA

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 
- Weight: 0.008 grams (Approximate)

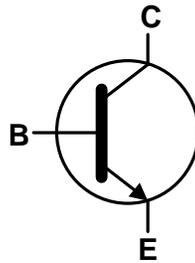
Applications

- Various Driving Functions Including Motors, Actuators, Solenoid and Relays
- Backlight Inverters
- DC-DC Modules

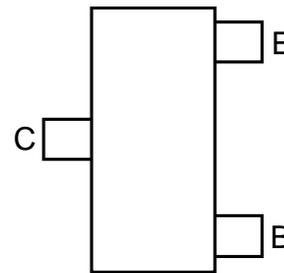
SOT23 (Type DN)



Top View



Device Symbol



Top View
Pin-Out

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	120	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	1	A
Peak Pulse Current	I_{CM}	2	A
Base Current	I_B	200	mA

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

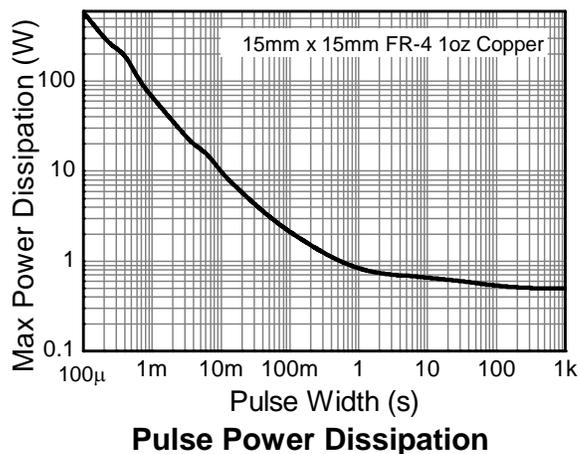
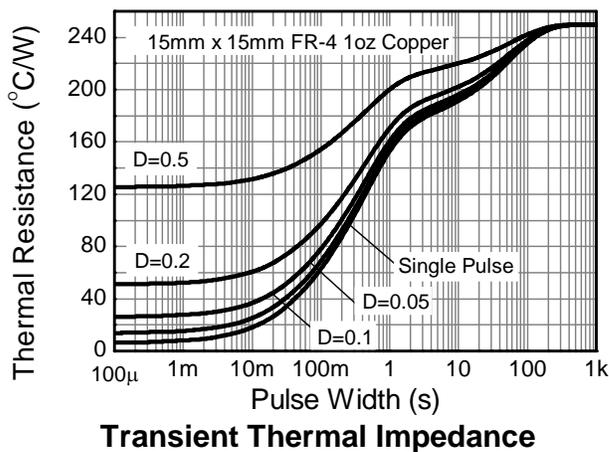
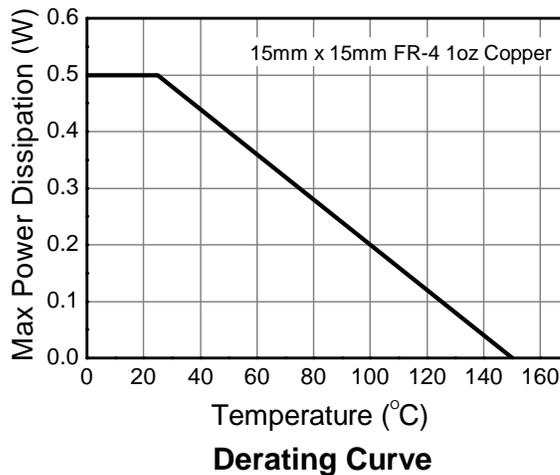
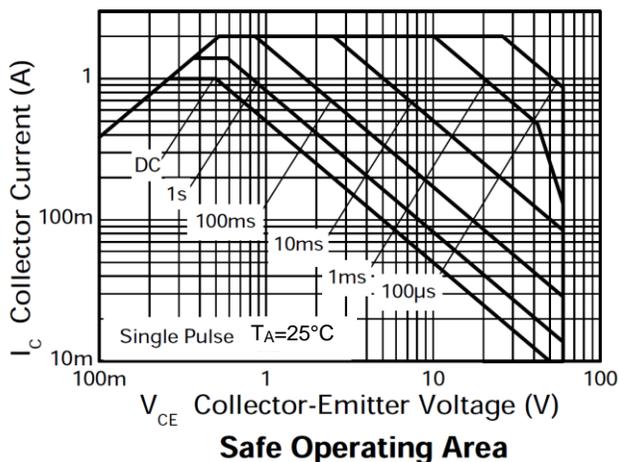
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	250	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Lead (Note 6)	$R_{\theta JL}$	197	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
5. For a device surface mounted on 15mm x 15mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

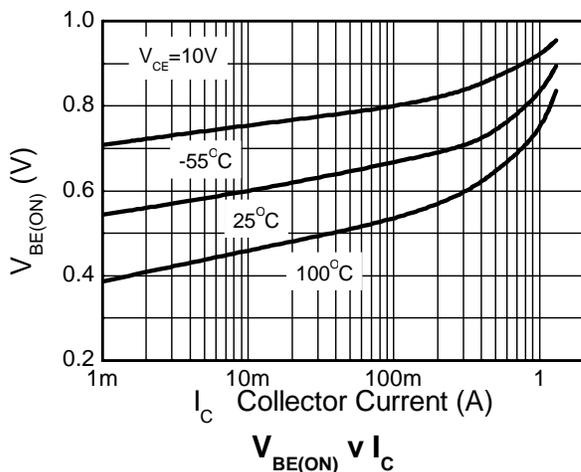
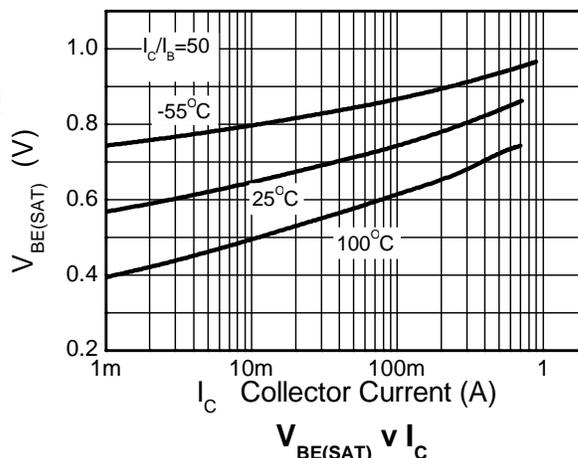
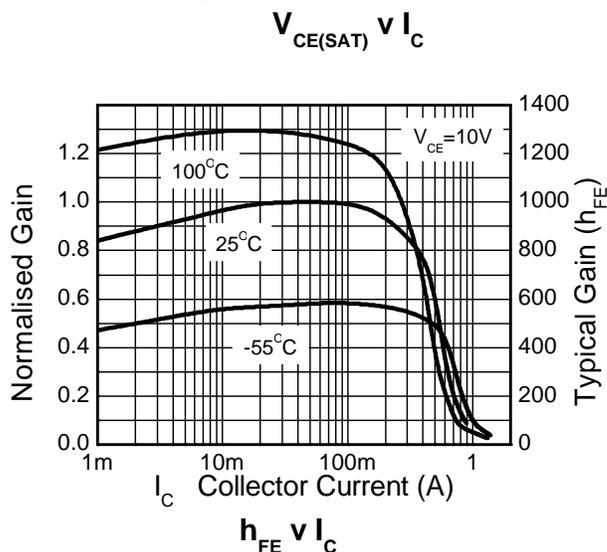
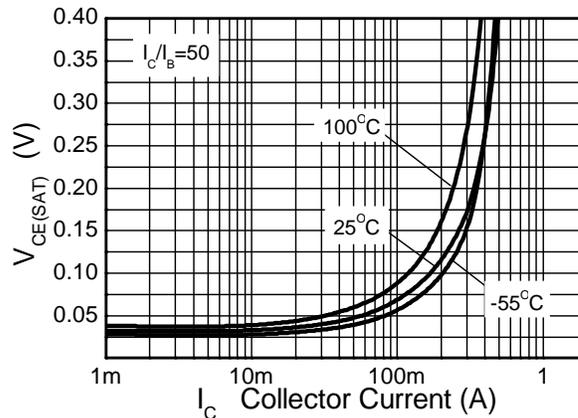
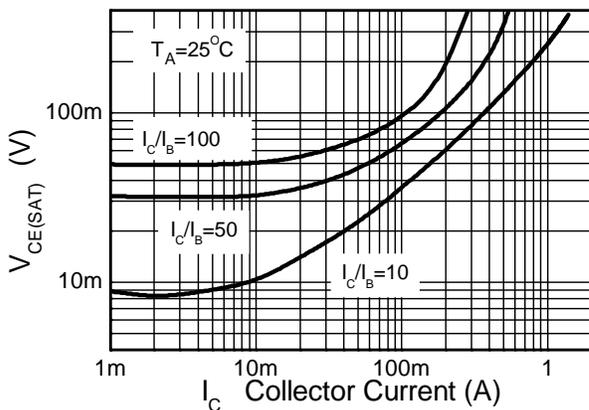


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	120	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	60	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	—	—	100	nA	V _{CB} = 45V
Emitter Cutoff Current	I _{EBO}	—	—	100	nA	V _{EB} = 4V
Collector Emitter Cutoff Current	I _{CES}	—	—	100	nA	V _{CE} = 45V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	300	—	—	—	I _C = 1mA, V _{CE} = 10V
		500	—	—		I _C = 150mA, V _{CE} = 10V
		300	—	1200		I _C = 250mA, V _{CE} = 10V
		100	—	—		I _C = 500mA, V _{CE} = 10V
		20	—	—		I _C = 1A, V _{CE} = 10V
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(SAT)}	—	—	250	mV	I _C = 500mA, I _B = 50mA
		—	—	500		I _C = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(ON)}	—	—	1.0	V	I _C = 1A, V _{CE} = 10V
Base-Emitter Saturation Voltage (Note 8)	V _{BE(SAT)}	—	—	1.15	V	I _C = 1A, I _B = 100mA
Output Capacitance	C _{obo}	—	—	10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	150	—	—	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz

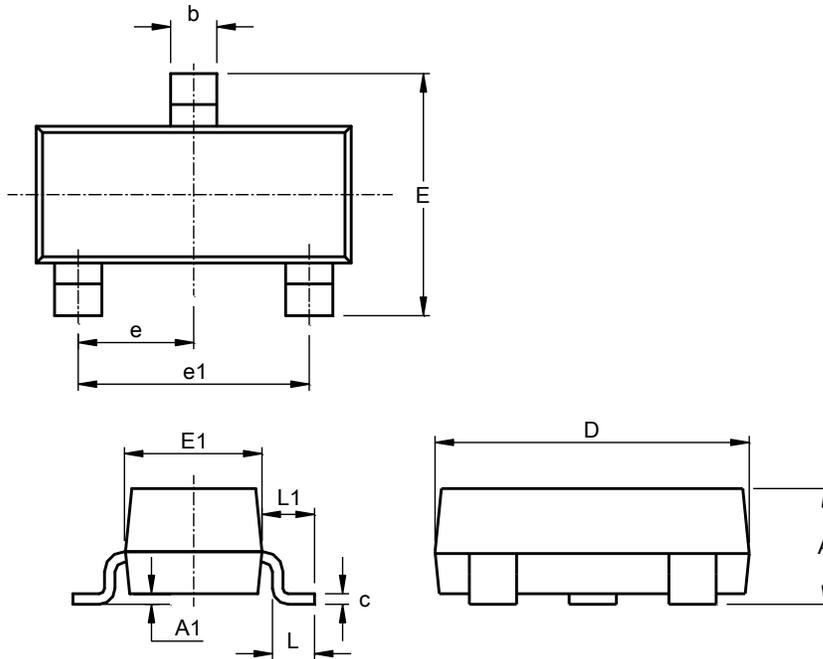
Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

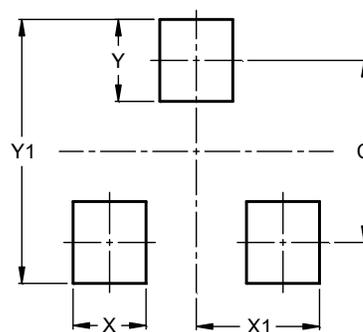
SOT23 (Type DN)



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Dim	Min	Max	Typ
A	0.89	1.12	1.00
A1	0.01	0.10	0.05
b	0.30	0.51	0.45
c	0.08	0.20	0.10
D	2.80	3.04	3.00
E	2.10	2.64	2.42
E1	1.20	1.40	1.37
e	0.95 REF		
e1	1.90 REF		
L	0.25	0.60	0.30
L1	0.45	0.62	0.54
All Dimensions in mm			

Suggested Pad Layout

SOT23 (Type DN)



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9